

### **30V Dual P-Channel Enhancement Mode MOSFET**

Voltage

-30 V

Current

-9A

### **Features**

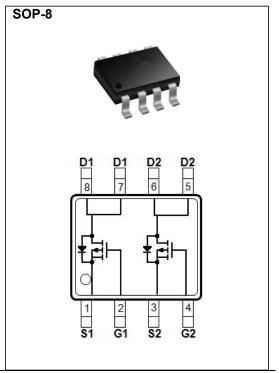
- $R_{DS(ON)}$ ,  $V_{GS}$ @-10V, $I_D$ @-9A<10.5m $\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V$ ,  $I_{D}@-7A<15m\Omega$
- · High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance

### **Mechanical Data**

• Case: SOP-8 package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0029 ounces, 0.083 grams



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAME <sup>*</sup>	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V <sub>DS</sub>	-30	V	
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 20	V	
Continuous Drain Current	T <sub>A</sub> =25°C		-9	A	
	T <sub>A</sub> =70°C	I <sub>D</sub>	-7		
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	-28	ı	
Power Dissipation	T <sub>A</sub> =25°C		1.25	W	
	T <sub>A</sub> =70°C	P <sub>D</sub>	0.8		
Operating Junction and Storage	$T_J, T_{STG}$	-55~150	°C		
Typical Thermal Resistance - Junction to Ambient (Note 5)		R <sub>eJA</sub>	100	°C/W	



## **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =-250uA	-30	-	-	5 V	
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250uA	-1.0	-1.5	-2.5		
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-9A	-	7	10.5	0	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-7A	-	12	15	mΩ	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V,V <sub>GS</sub> =0V	-	-	-1.0	uA	
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 6)							
Total Gate Charge	$Q_g$	\/ _ 45\/   _ 5A	-	11	-	nC	
Gate-Source Charge	$Q_{gs}$	V <sub>DS</sub> =-15V, I <sub>D</sub> =-5A, V <sub>GS</sub> =-4.5V (Note 1,2)	-	3.2	-		
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> 4.5V	-	3.9	-		
Input Capacitance	Ciss	\\ - 45\\ \\ -0\\	-	1169	-	pF	
Output Capacitance	Coss	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	180	-		
Reverse Transfer Capacitance	Crss	I-I.UIVITZ	-	132	-		
Turn-On Delay Time	td <sub>(on)</sub>	\/ - 45\/	-	5.9	-		
Turn-On Rise Time	tr	$V_{DS}$ =-15V, $I_{D}$ =-1A, $V_{GS}$ =-10V, $R_{G}$ =6 $\Omega$	-	33	-	ns	
Turn-Off Delay Time	td <sub>(off)</sub>	(Note 1,2)	-	55	-		
Turn-Off Fall Time	tf		-	34	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	l <sub>S</sub>				-7.8	А	
Diode Forward Current	IS						
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-1A, V <sub>GS</sub> =0V	-	-0.7	-1.0	V	

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial  $T_J$ =25°C.
- 5. Roja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.



### TYPICAL CHARACTERISTIC CURVES

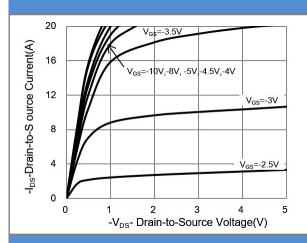
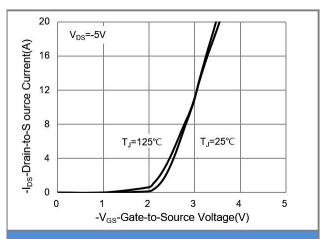


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

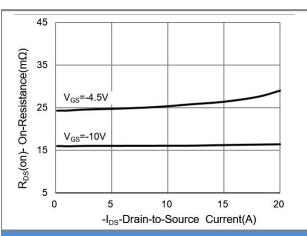


Fig.3 On-Resistance vs. Drain Current

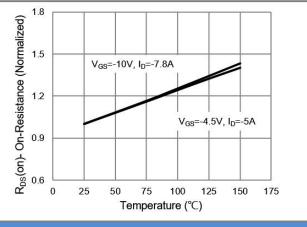
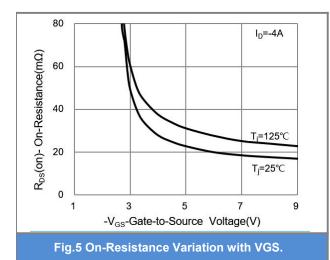


Fig.4 On-Resistance vs. Junction temperature

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0.01 T<sub>j</sub>=125°C T<sub>j</sub>=25°C T<sub>j</sub>=25°C

**Fig.6 Body Diode Characteristics** 



#### **TYPICAL CHARACTERISTIC CURVES**

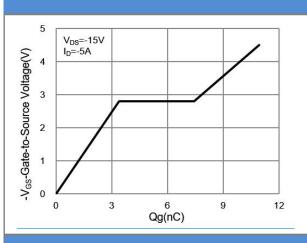
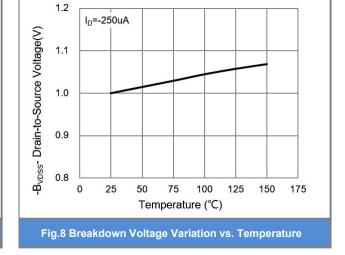


Fig.7 Gate-Charge Characteristics



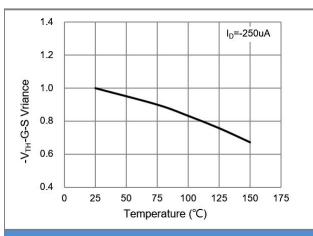


Fig.9 Threshold Voltage Variation with Temperature.

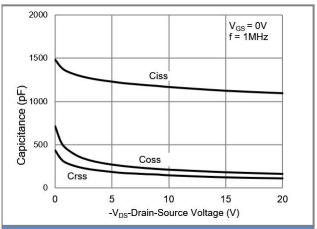


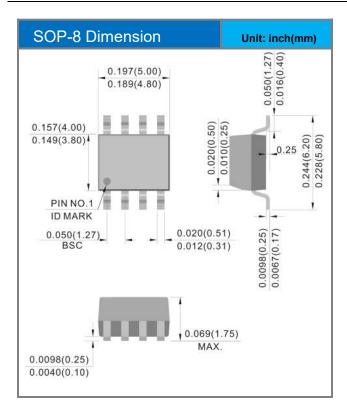
Fig.10 Capacitance vs. Drain-Source Voltage.

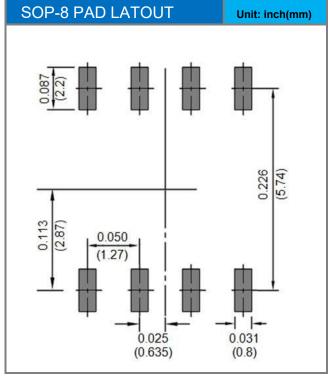


### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type		
CSM320PP9SOP8	SOP-8	2.5K pcs / 13" reel		

### **Packaging Information & Mounting Pad Layout**







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